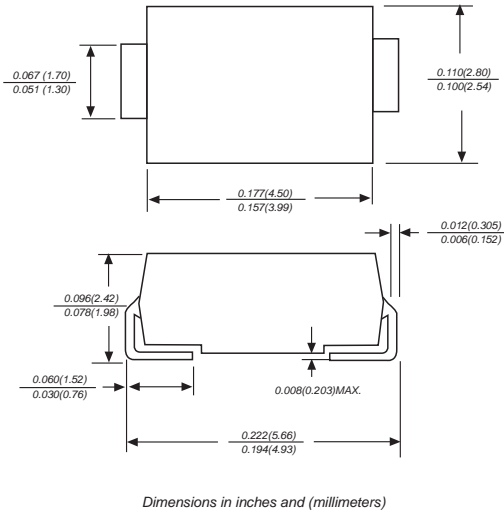




SS2150 THRU SS2200

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER
 Reverse Voltage - 150 to 200 Volts Forward Current - 2.0 Amperes

DO-214AC/SMA



FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
 250°C/10 seconds, 0.375" (9.5mm) lead length,
 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-214AC molded plastic body
Terminals: leads solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.002 ounce, 0.07 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

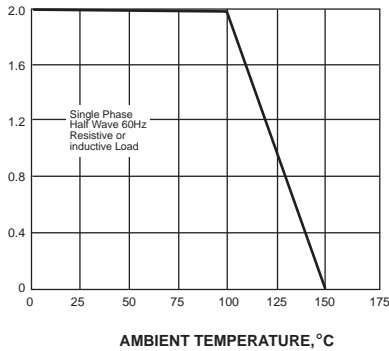
MDD Catalog Number	SYMBOLS	SS2150	SS2200	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	150	200	VOLTS
Maximum RMS voltage	V_{RMS}	105	140	VOLTS
Maximum DC blocking voltage	V_{DC}	150	200	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig. 1)	$I_{(AV)}$	2.0		Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50.0		Amps
Maximum instantaneous forward voltage at 2.0A	V_F	0.85	0.95	Volts
Maximum DC reverse current $T_A=25^\circ C$ at rated DC blocking voltage $T_A=100^\circ C$	I_R	0.2 2.0		mA
Typical junction capacitance (NOTE 1)	C_J	80		pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	88		°C/W
Operating junction temperature range	T_J	-65 to +150		°C
Storage temperature range	T_{STG}	-65 to +150		°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

RATINGS AND CHARACTERISTIC CURVES SS2150 THRU SS2200

AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

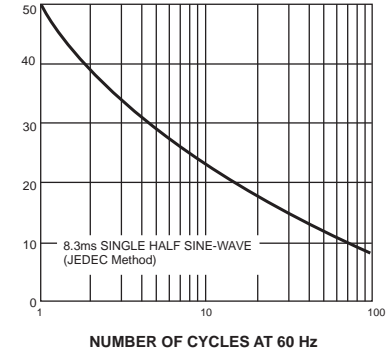
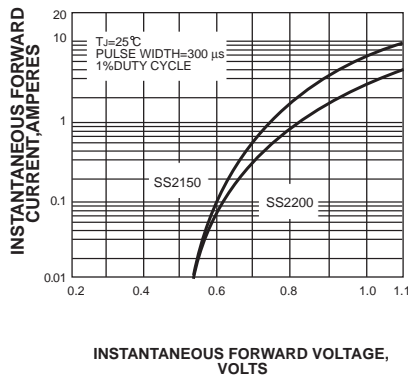


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

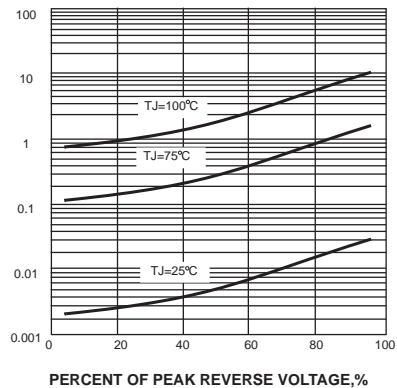
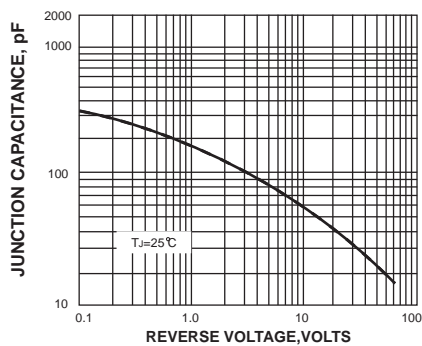
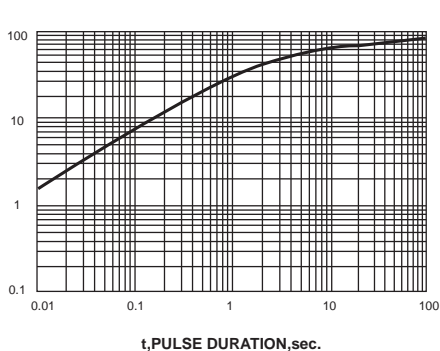


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



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